Layer-by-Layer Self-Assembled Single-Walled Carbon Nanotubes Based Ion-Sensitive Conductometric Glucose Biosensors

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Abstract—We present ion-sensitive conductometric glucose sensors prepared by layer-by-layer (LbL) nano self-assembly of single-walled carbon nanotube (SWNT) and enzyme glucose oxidase (GOx). The carboxylated SWNT and GOx are self-assembled alternatively with a positively charged polyelectrolyte, poly(diallyldimethylammonium chloride, PDDA). Quartz crystal microbalance (QCM) study and Fourier transform infrared (FTIR) spectroscopy demonstrate GOx is negatively charged, and it is possible to successively construct multilayer alternatively with PDDA. SWNT multilayer shows pH-dependent conductance at different pH buffer solutions, which decreases exponentially with an increase in pH. The concentration of glucose is electronically characterized based on the fact that hydrogen ions from glucose oxidation with the aid of GOx change the local pH value in the vicinity of SWNT multilayer thin-film, thereby yielding higher conductance. The overall sensitivity is 10.8 μA/mM and the resolution of device fabricated is 1 pM at the bias voltage of 0.6 V. The LbL assembled SWNT multilayer is proven to be versatile for sensing biochemical reactions with many other enzyme systems.

Index Terms—Fourier transform infrared (FTIR), glucose oxidase (GOx), glucose sensor, layer-by-layer (LbL) assembly, quartz crystal microbalance (QCM), single-walled carbon nanotube (SWNT).

I. INTRODUCTION

SINCE the discovery by Iijima [1] in 1991, carbon nanotubes (CNT) have been of great interest in many research and development areas due to the extraordinary mechanical and unique electronic property with the excellent thermal and chemical stability [2]. CNT becomes one of the promising functional materials for applications mostly to chemical [3] and biological sensors [4], actuators [5], nanoelectronics [6], nanoelectromechanical systems (NEMS) [7], and microscopy [8], etc.

The studies of the electrochemical property of CNTs substantially make them very useful for biosensing applications [9]. CNT-based biosensors reported detected protein [10], DNA [11], immunoglobulin [12], neurotransmitters [13] and other molecules [14] for the purpose of diagnostics in the presence or absence of bio-receptors, reacting specifically with target biomolecules.

The glucose sensors are in the forefront of recent advances in biosensors due to the high demand of diabetes diagnosis and the necessity of the monitoring glucose level in the fermentation process in the food industry. Most glucose sensors have been developed as an amperometric type, where electrons are transferred from the glucose to the modified metal electrode with or without the aid of glucose oxidase (GOx) as a catalyst. Emphasis has been placed on the surface modification of electrodes to increase the sensitivity and reduce the response time.

Among those, the surface modification by various functional nanomaterials has become the main stream of electrochemical sensors to exploit their novel properties. Multiwalled CNT (MWNT) modified glucose sensors showed higher sensitivity and longer stability than glassy carbon-based sensors [15]. As a further advance form, MWNTs were decorated with nanoparticles [16] and conducting polymers [17] to enhance the electrochemical property of CNTs themselves. Recently, combined with a facile layer-by-layer (LbL) self-assembly technique, CNT was deposited on the electrode surface to construct the glucose sensors alternated with GOx [18], gold nanoparticles [19], and both chitosan and GOx [20]. Other electrochemical glucose sensors are conductometric types based on ion-sensitive field effect transistors (ISFETs). Among those, nanomaterial-based glucose sensors were constructed using SiOx [21] and MnOx nanoparticles [22] in combination with GOx as a gate electrode. Our group previously reported nanoparticle-based glucose ISFET sensors with In2O3 as a semiconducting layer and SiO2 nanoparticles as a dielectric material [23].

To the best of our knowledge, however, there have not been LbL self-assembled thin-film planar conductometric glucose sensors. The planar devices are advantageous in that they can be used for continuous monitoring using the simplicity of the electronic detection and are low-cost due to the possibility of mass production [24]. Furthermore, it can be incorporated into implantable devices for possible in-vivo applications. In this paper, we describe a hydrogen ion-sensitive SWNT multilayer on which GOx enzymes were immobilized using a facile LbL assembly. The LbL assembled SWNT multilayer showed pH-dependent conductance, which decreases exponentially with increase in pH values due to protonation/deprotonation of a SWNT network. The pH changes induced in the process of
glucose oxidation by the enzyme GOx cause the conductance changes of SWNT multilayer, resulting in the current changes flowing through the multilayer.

II. EXPERIMENTAL

A. Materials

SWNTs (1–2 nm in diameter, 50 μm in length) were chemically functionalized with 3:1 mixture of concentrated sulfuric (H₂SO₄) and nitric acid (HNO₃) at 110 °C for an hour, followed by membrane filtering with the pores of 0.22 μm to remove soot, metallic particles, and shorter CNTs. After several rinsing with deionized water (DIH₂O) until the pH approached to 5, the functionalized SWNTs were harvested and redispersed into DIH₂O with the aid of ultra-sonication for an hour. The SWNT solution was centrifugated at a speed of 5000 rpm (4500 g, Eppendorf centrifuge 5804) for 20 min to eliminate longer CNTs, aggregates and bundles. Subsequently, the supernatant was carefully decanted and precipitated, aggregates and bundles were abandoned. The final concentration of a SWNT solution was about 0.06 wt%.

GOx (50 ku/g) from Aspergillus niger was purchased from Aldrich. The concentration of GOx solution used in this study was 1 mg/mL into 1X phosphate buffered solution (PBS, pH7.2). Polyelectrolytes used for LbL assembly were poly(diallyldimethyammonium chloride, PDDA, Mₘ = 200 ~ 350 k, Aldrich) and poly(stylenesulfonate, PSS, Mₘ = 70 k, Aldrich). The concentration of PDDA and PSS used was 1.4 wt% and 0.3 wt%, respectively, with 0.5 M sodium chloride (NaCl) for better surface coverage.

B. Device Fabrication

A standard 4 inch silicon (Si) wafer with silicon dioxide (SiO₂) 2 μm thick was cleaned in a piranha solution (3:H₂SO₄:H₂O₂) at 120 °C for 15 minutes, rinsed thoroughly with a copious amount of DIH₂O, and dried with a nitrogen (N₂) stream. Chromium (Cr, 100 nm) and gold (Au, 200 nm) were electron-beam evaporated onto the Si/SiO₂ substrate, and patterned for source-drain electrodes using photolithography. Another lithographic technique was used to fabricate a window area on which the LbL film was assembled and to protect the measuring pad from the adsorption of CNTs. After developing photoresist, oxygen (O₂) plasma was used to remove the residual photoresist completely in the opening window at a power of 100 W for 1 minute with O₂ flow rate of 100 sccm as well as to make the surface hydrophilic, which is essential for subsequent LbL assembly.

Two bi-layers of (PDDA/PSS) were self-assembled as a precursor layer on the patterned substrate for charge enhancement, followed by the assembly of (PDDA/SWNT)₃ as a transducer material. Following SWNT multilayer, three bi-layers of (PDDA/GOx) were LbL-assembled as bio-receptors. The dipping time used here was 10 min for polyelectrolytes and GOx, and 15 min for SWNT. The schematic diagram of the LbL assembled SWNT and GOx based glucose sensor is shown in Fig. 1. There are three different layers, (PDDA/PSS)₂ as a precursor layer for the charge enhancement, (PDDA/SWNT)₃ as an electrochemical transducer, and (PDDA/GOx)₃ as a bio-receptor.
C. Quartz Crystal Microbalance (QCM) Measurement

The whole process for LbL assembly of both SWNT transducing layers and GOx bio-receptors was monitored by quartz crystal microbalance (RQCM, Maxtek Inc.) at room temperature. The used crystal is the AT cut 9 MHz with the active oscillation area of 0.34 cm².

First of all, two bi-layers of (PDDA/PSS) were deposited on the 9 MHz crystal for the charge enhancement of the crystal surface, followed by 5 bi-layers of (PDDA/SWNT) as the transducer materials. Finally, GOx was assembled on the SWNT layer alternatively with PDDA. After every layer, thorough washing with DIH₂O was performed to prevent precipitations, which hamper uniform coating of subsequent materials, followed by a nitrogen (N₂) drying. This QCM characterization simulated the exact process of the fabrication of glucose sensors. Frequency shift after the assembly of each layer was monitored and recorded with the sampling frequency of 1.25 kHz.

D. Fourier Transform Infrared (FTIR) Spectroscopy

A silicon wafer with silicon dioxide 2 µm thick was cleaned with piranha as aforementioned to remove the organic contaminants. To demonstrate the assembly of GOx onto PDDA terminated surface, GOx was assembled with an alternative layer of PDDA after depositing two bi-layers of (PDDA/PSS). The reflective FTIR (Nicolet Magna IR 750) spectroscopy was used to characterize PDDA, (PDDA/PSS), and (PDDA/PSS)₂(PDDA/GOx) surfaces with the background of the bare SiO₂ surface. FTIR spectra were obtained in the mid-infrared (MIR) region, 4000–1000 cm⁻¹ by an average of 500 scans with a spectral resolution of 2 cm⁻¹.

E. Electronic Characterization

The fabricated sensors were dipped into at different pH buffer solutions (mixture of KH₂PO₄ and K₂HPO₄) with buffer strength of 50 mM to demonstrate pH-dependent conductance behavior of SWNT transducing layers. The resistance of the device was recorded with the time using data logging system (Agilent 34970A Data acquisition/switch unit) and was converted into the conductance. In addition, J-V characteristics was measured using semiconductor parameter analyzer (HP 4156A) at different pH buffer solutions over the range of biochemical reactions. For glucose detection, three different kinds of devices (the ones only with GOx, the ones only with SWNT, and the ones with both SWNT and GOx) were prepared to show that the combination of SWNT and GOx plays a key role of glucose sensing. Furthermore, devices were characterized using parameter analyzer at different glucose concentration on the physiological ranges (2–10 mM) dissolved in phosphate buffered saline (PBS), as well as low concentration to evaluate the performance of the fabricated sensors. The characterized devices were stored at 4 °C for 15 days and recharacterized to investigate the stability of devices.

III. RESULTS AND DISCUSSION

The fabricated devices on the standard 4 inch wafer and individual chips are shown in Fig. 2, where only two terminal devices are used. To characterize the SWNT terminated surface with Scanning electron microscope (SEM, Jeol 6500), the surface of (PDDA/PSS)₂(PDDA/SWNT)₅ were sputter-coated with platinum 50 Å thick. SEM images were obtained at an acceleration voltage of 10 kV, as shown in Fig. 3. The individual SWNTs as well as their bundles are observed and they form a random network.

The QCM characterization result for the whole LbL assembly process of glucose sensor is shown in Fig. 4. It is clearly observed that the frequency decreases with the number of layers assembled, as shown in Fig. 4(a). The reason for the abrupt frequency increase corresponding to PDDA assembly after PSS, SWNT, and GOx is the viscosity of PDDA solution since frequency shift was collected in the solution not in the atmosphere. It assures exclusion of the effect of any moisture left after intermediate drying and contaminants adsorption from the atmosphere. The saturated frequency shifts are shown in Fig. 4(b). The average frequency shifts of either polycation like PDDA or polyanion such as PSS, SWNT, and GOx reveal the mass adsorbed on the surface in Sauerbrey equation, given by

\[ \Delta f = -C_f \Delta m_s \]

where \( \Delta f \) is frequency shift in Hz, \( C_f \) sensitivity factor of the used crystal (0.181 Hz·cm²·ng⁻¹ for the 9 MHz AT cut crystal), and \( \Delta m_s \) mass adsorbed per unit area in ng/cm².
This is based on the fact that the crystal is fully covered with the materials assembly [25] and sustained by fully distributed SWNTs, as shown in Fig. 3. The averages of frequency shifts for (PDDA/PSS), (PDDA/SWNT), and (PDDA/GOx) bi-layers are 198, 299, and 65 Hz, respectively. In particular, the frequency decrease for (PDDA/SWNT) bi-layer is substantially consistent with the previous result [26]. The mass of assembled bi-layers, (PDDA/PSS), (PDDA/SWNT), and (PDDA/GOx) are calculated as 83, 125, and 27 ng, respectively. In addition, the thickness for each material can be calculated with the assumed density. The thicknesses for PDDA and SWNT are 2.8 and 4.8 nm, respectively [26]. Based on the assumed density, 1.3 g/cm$^3$ [27], the bio-receptor thicknesses can be calculated as 2.8 nm under assumption that linear polyelectrolyte (PDDA) fully covers GOx, so that only GOx size is dominant. The smaller film thickness than actual diameter of GOx (∼7 mm) can be attributed to the sparse packing of GOx on the surface. From the QCM data, it is obvious that GOx is negatively charged, and multilayer can be built up alternatively with positively charged PDDA.

Complementary to QCM, FTIR was used to demonstrate GOx could be self-assembled onto the positively charged PDDA surfaces. The reflective FTIR spectra of PDDA, (PDDA/PSS), and (PDDA/PSS)$_2$(PDDA/GOx) are shown in Fig. 5. Unlike the spectra of PDDA and (PDDA/PSS) control groups, the spectrum of GOx surface has several characteristic peaks. The strong absorption peak at 1664 cm$^{-1}$ corresponds to C=O stretching vibration (amide I band, 1700–1600 cm$^{-1}$) of peptide bonds of GOx backbone absorbed onto PDDA surface. Another strong peak at 1520 cm$^{-1}$ results from N-H bending vibration (amide II band, 1600–1500 cm$^{-1}$) of peptide bonds. Both strong peaks are in good agreement with reported results [28]. These two peaks are evident indications of the presence of GOx. Moreover, the weak peak at 3320 cm$^{-1}$ is caused by N-H stretching of the peptide backbone, and peaks ranging from 1300–1240 cm$^{-1}$ are attributed to amide band III [29]. In consequence, the absorption peaks found in the (PDDA/PSS)$_2$(PDDA/GOx) compared to PDDA and (PDDA/PSS) ensure that enzyme GOx is negatively charged, and can be self-assembled alternatively with positively charged PDDA. Furthermore, FTIR is proven to be a potent tool to demonstrate the protein immobilized by LbL assembly, since it has been used for determination of protein secondary structure [29].

The electronic detection of pH responses is depicted in Fig. 6. The temporal responses of the conductance of (PDDA/PSS)$_2$(PDDA/SWNT)$_5$ device is shown in Fig. 6(a). In the atmosphere, the conductance was collected until it had been stabilized, and pH buffer solution was added. After the signal was stabilized in the buffer, the old buffer solution was removed and new buffer was added at the same time. The conductance of SWNT multilayer decreases exponentially, which had the time constant of 15 s. The inset shows the current after adding pH6 buffer solution and its curve fitting to exponential decaying function. Therefore, 1 min after adding the sample solution was allowed for the stabilization of signals in the following detection using parameter analyzer. In Fig. 6(b), $I$-$V$ characteristics at different pH buffer are shown. It is noted that the current flowing through SWNT multilayer decreases with increase in pH at the same bias voltage. Replotting into current versus pH tells us that the current exponentially decreases as pH increases, which is well adapted to exponential function, as shown in Fig. 6(c). The effect of the ionic conductor due to buffer solutions used is negligible for transferring charge carriers at the low bias voltage. For this reason, hydrogen ions play a key role in changing the conductance of SWNT multi-

![Fig. 3. Scanning electron microscopy (SEM) image of SWNT terminated surface. Individual SWNTs, bundles, and their random network are observed.](image-url)
layer assuming the same effects of other ions. In particular, the conductance of SWNT multilayer is believed to have something to do with protonation/deprotonation of carboxylic group in SWNTs as Henderson–Hasselbach equation implies, under the assumption that the acidities of all carboxylic groups in SWNTs are the same. The protonation/deprotonation in carboxylated SWNTs might be explained as the hole doping/undoping of semiconducting SWNTs from the conventional semiconductor perspectives [30], because carboxylated and LbL assembled CNTs have been proven to be p-type semiconductor [31].

The glucose testing of LbL assembled devices is shown in Fig. 7. All data of current versus glucose concentration were collected using the semiconductor parameter analyzer. First of all, (PDDA/PSS)\(_2\) (PDDA/SWNT)\(_{15}\) and (PDDA/PSS)\(_2\) (PDDA/GO\(_x\))\(_{3}\) has been chosen as control groups in the absence of the bio-receptor and transducer, respectively, in order to demonstrate that the combination of SWNT and GO\(_x\) shows the capabilities of glucose sensing. The currents are depicted in Fig. 7(a) at a bias voltage of 0.6 V. The current in (PDDA/PSS)\(_2\) (PDDA/GO\(_x\))\(_3\) is almost constant at zero compared to other two groups, indicating that other salt ions do not play a significant role of transferring charge carriers between source and drain electrodes. On the other hand, the current in devices with only SWNT multilayer diminishes almost linearly with the increase of glucose concentration presumably due to the adsorption of glucose molecules onto SWNT surface and/or changes of the proximal ionic environment. Contrary to these, it is explicitly observed that the cooperation of SWNT and GO\(_x\) shows the augmenting current with glucose concentration as previous discussions described elsewhere, as shown below [21], [23]

\[
\beta \rightarrow D - \text{glucose} + O_2 \rightarrow \text{GO}x
\]

\[
D - \text{gluco} \rightarrow \delta - \text{lactone} + H_2O_2
\]

\[
D - \text{gluco} \rightarrow \delta - \text{lactone} + H_2O \rightarrow D - \text{gluconate}^- + H^+.
\]

\(\beta\)-D-glucose is oxidized to D-glucono-\(\delta\)-lactone with the aid of GO\(_x\), followed by the hydrolysis to produce hydrogen ions. Based on the pH-dependent conductance changes in SWNT multilayer, the current flowing through the multilayer is dependent on glucose concentrations. Even though the pH in the bulk solution maintains relatively constant owing to buffering power of PBS, the local pH changes near GO\(_x\) leads to protonation/deprotonation of carboxylic groups on SWNTs causing the conductance variation. Moreover, the effect of bias voltage on the current is shown in Fig. 7(b). As driving voltage increases, the current increases. It is expected that the sensitivity increases with glucose concentration at the constant bias voltage. However, it is worthy of mentioning that the sensitivity in the glucose sensing decreases with glucose concentration, as shown in Fig. 7(c), which is opposed to pH-responsive conductance behavior in Fig. 6(b). The decreasing sensitivity is caused by the enzyme GO\(_x\) kinetics since the current corresponds to the rate of reaction and it is obviously enzyme limited, which has been proven in QCM results. The overall sensitivity upon
linear fitting has been found as $10.8 \mu A/mM$ at the bias voltage of 0.6 V. The sensitivity found in this study is remarkable compared to other planar devices reported previously [23], [32], [33] due to the highly sensitive SWNTs. The resolution of device fabricated is shown in Fig. 8 at the bias voltage of 0.6 V. Even though it shows a different current level and scale from the ones in Fig. 7, which was measured in the different chip, it is observed that the device can detect down to 1 pM glucose concentration presumably due to highly sensitive SWNTs. In addition, the result for the stability test is shown in Fig. 9. The device was stored in the refrigerator at 4 °C. The decreased overall sensitivity from 9.5 to 8.6 $\mu A/mM$ is observed due to decreased enzyme activity, but the current level is increased 15
14.8 µA/mM and 1 pM, respectively, at the bias of 0.6 V.

Fig. 8. Resolution test of the fabricated glucose sensor at the voltage of 0.6 V.

Fig. 9. Stability test of the fabricated glucose sensor stored in dry state at 4°C.

days after fabrication presumably due to surface adsorption of the atmospheric particles or surface oxidation.

IV. CONCLUSION

We have fabricated the conductometric glucose sensors using LbL assembled SWNT and GOx. The GOx has been proven to be charged negatively and assembled successively using LbL technique as shown in FTIR and QCM results. LbL assembled thin-film SWNT multilayer shows exponential pH-dependent conductance by protonation/deprotonation of carboxylic functional groups on the SWNTs. Hydrogen ions penetrate into SWNT multilayer and have influence on its electronic conductance. Based on conductance change caused by pH change, glucose concentration can be detected by the local pH changes, which is caused basically by the oxidation of glucose catalyzed by GOx. The overall sensitivity and the resolution of device fabricated are 10.8 µA/mM and 1 pM, respectively, at the bias voltage of 0.6 V. LbL assembled SWNT thin-film multilayer may detects many other biochemical reactions accompanied by pH change assisted by enzymatic reactions.

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REFERENCES


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